

Amendments to the Specification:

Please replace paragraph [0012] with the following amended paragraph:

[0012] According to the claimed invention, a pixel structure of an active matrix display device is provided. The pixel structure includes a storage capacitor, a first active device, and a plurality of active-type light emitting devices. The active-type light emitting devices electrically are connected in parallel with each other, and each of the active-type light emitting devices is connected between a source of first potential and a source of second potential. The first active device has a first end electrically connected to a scanning line, a second end electrically connected to a data line, and a third end electrically connected to a switching end of each of the active-type light emitting devices for switching ~~all~~each of the active-type light emitting devices simultaneously. The storage capacitor has a first electrode electrically connected to the third end of the first active device and the switching end of the active-type light emitting devices, and a second electrode electrically connected to the source of first potential end.

Please replace paragraph [0022] with the following amended paragraph:

[0022] Please refer to Fig.6. Fig.6 is a circuit diagram of one of the pixels 52 shown in Fig.5. As shown in Fig.6, the pixel 52 comprises a storage capacitor 54, an active device 56, and a plurality of active-type light emitting devices 58 that are connected in parallel with each other for switching ~~all~~each of the active-type light emitting devices 58 simultaneously. Each active-type light emitting device 58 comprises an active device 60 (T1, T2, T3 or T4) and a light emitting device 62 (D1, D2, D3 or D4). The active-type light emitting devices 58 are electrically connected between a potential source 64, a potential source 66, and a first electrode 54a of the storage capacitor 54. Additionally, the potential source 64 is used to supply a potential V1, while the potential source 66 is used to supply a potential V2 that is a reference potential (ex.

grounding potential) and is usually smaller than V1. Furthermore, each of the active devices 56, 60 is a thin film transistor or a complementary metal-oxide semiconductor (CMOS), and each of the light emitting devices 62 is an organic light emitting diode or a light emitting diode (LED).